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# Octal D-type flip-flop; positive edge-trigger; 3-stateRev. 02 — 8 November 2007Product

Product data sheet

#### **General description** 1.

The 74ALVC574 is an octal D-type flip-flop featuring separate D-type inputs for each flip-flop and 3-state outputs for bus-oriented applications. A clock input (CP) and an outputs enable input  $(\overline{OE})$  are common to all flip-flops.

The eight flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW to HIGH CP transition.

When pin OE is LOW, the contents of the eight flip-flops is available at the outputs. When pin  $\overline{OE}$  is HIGH, the outputs go to the high-impedance OFF-state. Operation of the  $\overline{OE}$ input does not affect the state of the flip-flops.

The 74ALVC574 is functionally identical to the 74ALVC374, but has a different pin arrangement.

#### 2. **Features**

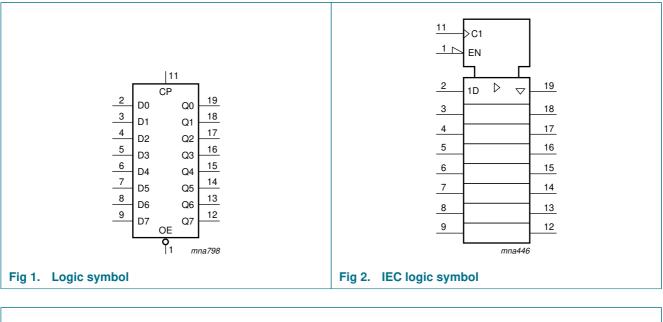
- Wide supply voltage range from 1.65 V to 3.6 V
- 3.6 V tolerant inputs/outputs
- CMOS low power consumption
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Power-down mode
- Latch-up performance exceeds 250 mA
- Complies with JEDEC standards:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115A exceeds 200 V

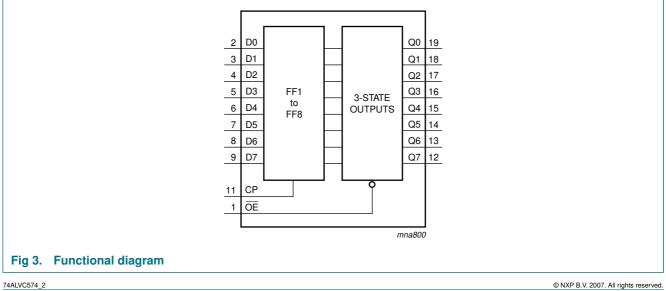


#### **Ordering information** 3.

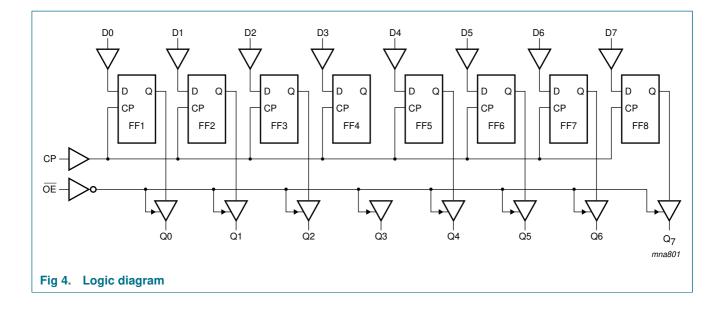
Table 1. Orde	ering information	Table 1. Ordering information								
Type number	Package									
	Temperature range	Name	Description	Version						
74ALVC574D	–40 °C to +85 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1						
74ALVC574PW	–40 °C to +85 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1						
74ALVC574BQ	–40 °C to +85 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm	SOT764-1						

#### **Functional diagram** 4.





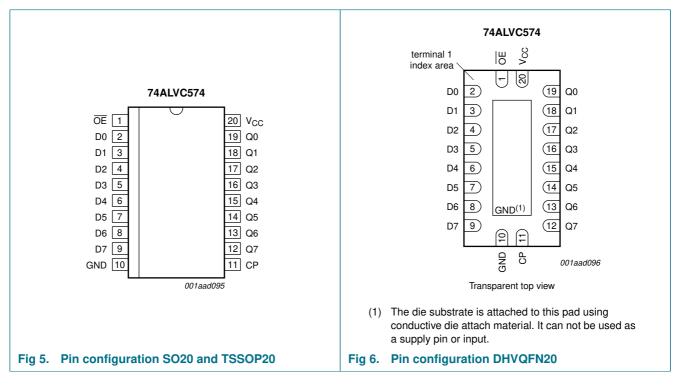
Octal D-type flip-flop; positive edge-trigger; 3-state



Octal D-type flip-flop; positive edge-trigger; 3-state

## 5. Pinning information

## 5.1 Pinning



## 5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
D[0:7]	2, 3, 4, 5, 6, 7, 8, 9	data input
CP	11	clock input (LOW to HIGH, edge-triggered)
ŌĒ	1	output enable input (active LOW)
Q[0:7]	19, 18, 17, 16, 15, 14, 13, 12	3-state flip-flop output
V <sub>CC</sub>	20	supply voltage
GND	10	ground (0 V)

## 6. Functional description

#### Table 3.Function table<sup>[1]</sup>

Operating mode	Input		Internal flip-flop	Output	
	OE	СР	Dn		Qn
Load and read register	L	Î↑	I	L	L
	L	Ŷ	h	Н	Н
Load register and disable	Н	$\uparrow$	I	L	Z
outputs	Н	Ŷ	h	Н	Z

[1] H = HIGH voltage level

h = HIGH voltage level one set-up time prior to the LOW to HIGH CP transition

L = LOW voltage level

I = LOW voltage level one set-up time prior to the LOW to HIGH CP transition

Z = high-impedance OFF-state

 $\uparrow$  = LOW to HIGH clock transition

## 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < 0 V		-50	-	mA
VI	input voltage			-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
Vo	output voltage	output HIGH or LOW state	[1] [2]	-0.5	$V_{CC} + 0.5$	V
		output 3-state		-0.5	+4.6	V
		power-down mode, $V_{CC} = 0 V$	[2]	-0.5	+4.6	V
lo	output current	$V_{O} = 0 V$ to $V_{CC}$		-	±50	mA
I <sub>CC</sub>	supply current			-	100	mA
I <sub>GND</sub>	ground current			-100	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C$	[3]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When  $V_{CC} = 0 V$  (power-down mode), the output voltage can be 3.6 V in normal operation.

[3] For SO20 packages: above 70 °C derate linearly with 8 mW/K.
 For TSSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.
 For DHVQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

Octal D-type flip-flop; positive edge-trigger; 3-state

## 8. Recommended operating conditions

Table 5.	Recommended operating condit	ions			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	output HIGH or LOW state	0	V <sub>CC</sub>	V
		output 3-state	0	3.6	V
		power-down mode; $V_{CC} = 0 V$	0	3.6	V
T <sub>amb</sub>	ambient temperature	in free air	-40	+85	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC}$ = 1.65 V to 2.7 V	0	20	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	0	10	ns/V

## 9. Static characteristics

#### Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	
VIH	HIGH-level input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$	-	-	V
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	1.7	-	-	٧
		$V_{CC} = 2.7 V \text{ to } 3.6 V$	2.0	-	-	٧
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 1.65 \text{ V}$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC}$ = 2.7 V to 3.6 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_O$ = $-100~\mu\text{A};$ $V_{CC}$ = 1.65 V to 3.6 V	$V_{CC}-0.2$	-	-	V
		$I_{O} = -6 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.25	1.51	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	2.10	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.7	2.01	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	2.53	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	2.76	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.2	2.68	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O$ = 100 $\mu A;V_{CC}$ = 1.65 V to 3.6 V	-	-	0.2	V
		$I_{O} = 6 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	0.11	0.3	V
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.17	0.4	V
		$I_{O} = 18 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	0.25	0.6	V
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	0.16	0.4	V
		$I_{O} = 18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.23	0.4	V
		$I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	0.30	0.55	V
l <sub>l</sub>	input leakage current	$V_{CC} = 3.6 \text{ V}; \text{ V}_{I} = 3.6 \text{ V} \text{ or GND}$	-	±0.1	±5	μA

## Octal D-type flip-flop; positive edge-trigger; 3-state

Symbol	Parameter	Conditions	-4	0 °C to +85	°C	Unit
			Min	Typ[1]	Max	
I <sub>OZ</sub>	OFF-state output current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL}; \ V_{CC} = 1.65 \ V \ \text{to} \ 3.6 \ V; \\ V_{O} = 3.6 \ V \ \text{or } \ GND; \end{array}$	-	±0.1	±10	μA
I <sub>OFF</sub>	power-off leakage current	$V_{CC} = 0 \text{ V}; \text{ V}_{1} \text{ or } \text{ V}_{O} = 0 \text{ V to } 3.6 \text{ V}$	-	±0.1	±10	μA
I <sub>CC</sub>	supply current	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 3.6 \ V; \ V_I = V_{CC} \ \text{or GND}; \\ I_O = 0 \ A \end{array}$	-	0.2	10	μA
$\Delta I_{CC}$	additional supply current	per input pin; V <sub>CC</sub> = 3.0 V to 3.6 V; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A	-	5	750	μA
CI	input capacitance		-	3.5	-	pF

#### Table 6. Static characteristics ... continued

[1] All typical values are measured at V<sub>CC</sub> = 3.3 V (unless stated otherwise) and T<sub>amb</sub> = 25 °C.

## **10. Dynamic characteristics**

#### **Dynamic characteristics** Table 7.

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

Symbol	Parameter	Parameter Conditions		-40	) °C to +85	5 °C	Unit
						Max	
t <sub>pd</sub>	propagation delay	CP to Qn; see Figure 7	[2]				
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		1.0	3.1	6.4	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.0	2.3	3.9	ns
		$V_{CC} = 2.7 V$		1.0	2.5	3.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.0	2.5	3.6	ns
t <sub>en</sub>	enable time	OE to Qn; see Figure 8	[2]				
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.0	3.2	6.4	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.0	2.6	4.5	ns
		$V_{CC} = 2.7 V$		1.0	3.2	4.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.0	2.4	4.0	ns
dis	disable time	OE to Qn; see Figure 8	[2]				
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.5	3.6	7.0	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.0	2.3	4.4	ns
		$V_{CC} = 2.7 V$		1.5	2.9	4.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.0	2.8	4.4	ns
tw	pulse width	clock HIGH or LOW; see Figure 7					
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		3.8	1.1	-	ns
		$V_{CC}$ = 2.3 V to 2.7 V		3.3	0.9	-	ns
		$V_{CC} = 2.7 V$		3.3	0.8	-	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		3.3	1.2	-	ns

### Octal D-type flip-flop; positive edge-trigger; 3-state

Symbol	Parameter	Conditions	-40	0 °C to +85	5 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	
t <sub>su</sub>	set-up time	Dn to CP; see Figure 9				
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.8	-0.1	-	ns
	V <sub>CC</sub> = 2.3 V to 2.7 V	0.8	0.1	-	ns	
		$V_{CC} = 2.7 V$	0.8	0.3	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.8	0.0	-	ns
t <sub>h</sub>	hold time	Dn to CP; see Figure 9				
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.8	-0.1	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0.8	0.1	-	ns
		V <sub>CC</sub> = 2.7 V	0.8	0.4	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.7	-0.1	-	ns
f <sub>max</sub>	maximum frequency	see Figure 7				
		V <sub>CC</sub> = 2.3 V to 2.7 V	100	200	-	MHz
		V <sub>CC</sub> = 2.7 V	100	200	-	MHz
		V <sub>CC</sub> = 3.0 V to 3.6 V	150	300	-	MHz
C <sub>PD</sub>	power dissipation	per flip-flop; $V_I = GND$ to $V_{CC}$ ; $V_{CC} = 3.3$ V [3]				
	capacitance	outputs HIGH or LOW state	-	21	-	pF
		outputs 3-state	-	13	-	pF

#### Table 7. Dynamic characteristics ... continued

Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 10.

[1] Typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ 

t<sub>pd</sub> is the same as t<sub>PHL</sub> and t<sub>PLH</sub>.
 t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.
 t<sub>dis</sub> is the same as t<sub>PHZ</sub> and t<sub>PLZ</sub>.

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz

 $C_L$  = output load capacitance in pF

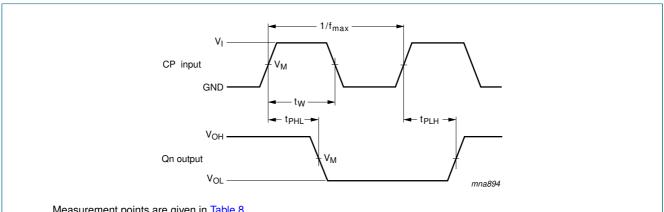
 $V_{CC}$  = supply voltage in Volts

N = number of inputs switching

 $\Sigma(C_L \times V_{CC}{}^2 \times f_o)$  = sum of the outputs

Octal D-type flip-flop; positive edge-trigger; 3-state

## 11. Waveforms



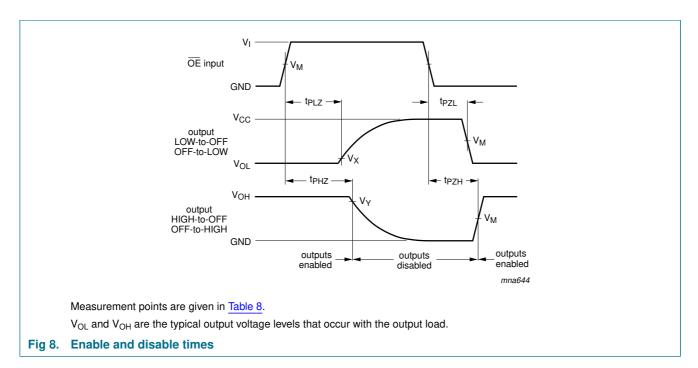
Measurement points are given in Table 8.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are the typical output voltage levels that occur with the output load.

### Fig 7. Clock (CP) to output (Qn) propagation delays, the clock pulse width, and the maximum frequency

#### Table 8. **Measurement points**

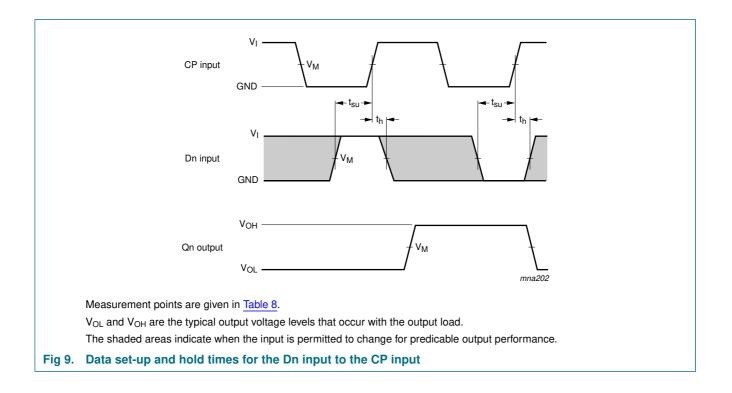
Supply voltage	Innut	Output		
Supply voltage	Input	Output		
V <sub>cc</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
1.65 V to 1.95 V	$0.5V_{CC}$	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
2.3 V to 2.7 V	$0.5V_{CC}$	0.5V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
2.7 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V
3.0 V to 3.6 V	1.5 V	1.5 V	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V



## **NXP Semiconductors**

# 74ALVC574

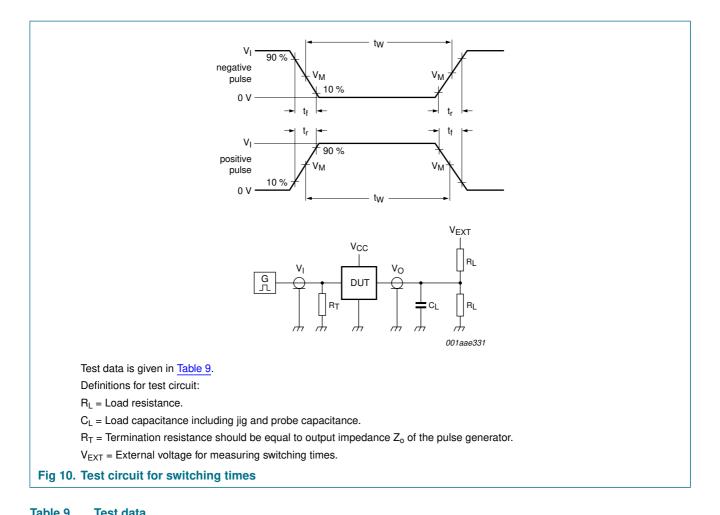
#### Octal D-type flip-flop; positive edge-trigger; 3-state



## **NXP Semiconductors**

# 74ALVC574

### Octal D-type flip-flop; positive edge-trigger; 3-state



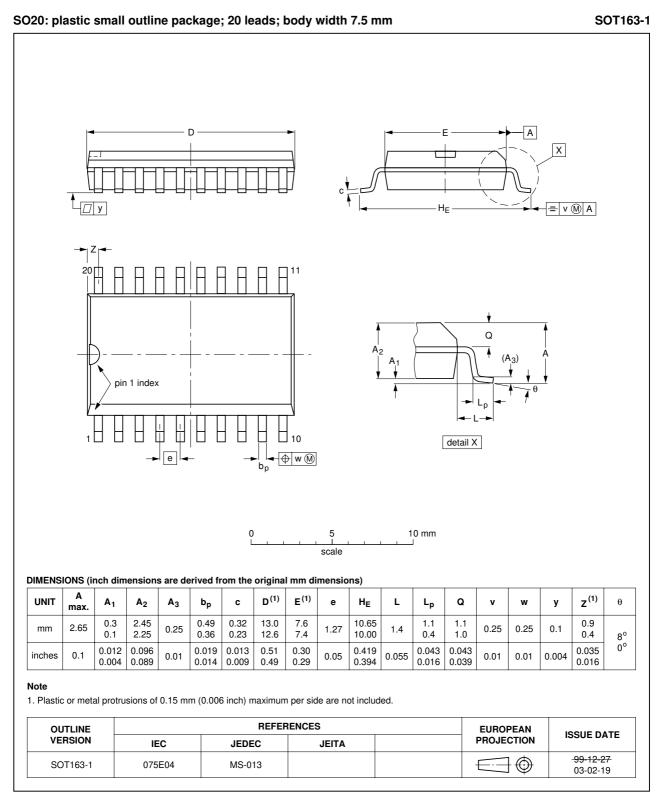
Supply voltage	Input	Input		Load		V <sub>EXT</sub>		
	Vi	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PHZ</sub> , t <sub>PZH</sub>	
1.65 V to 1.95 V	V <sub>CC</sub>	≤ 2.0 ns	30 pF	1 kΩ	open	2V <sub>CC</sub>	GND	
2.3 V to 2.7 V	V <sub>CC</sub>	$\leq$ 2.0 ns	30 pF	500 Ω	open	2V <sub>CC</sub>	GND	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	6 V	GND	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open	6 V	GND	

## **NXP Semiconductors**

## 74ALVC574

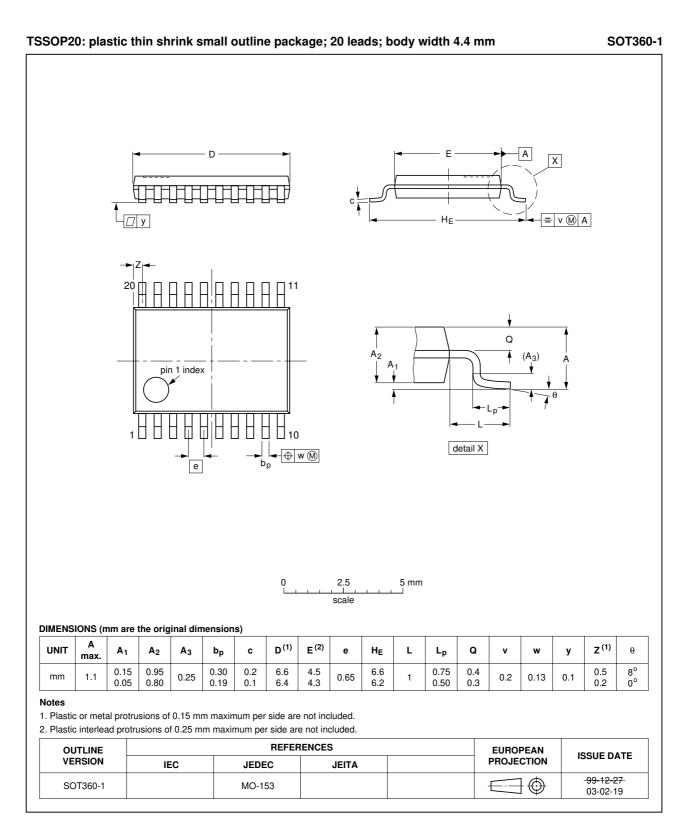
Octal D-type flip-flop; positive edge-trigger; 3-state

## 12. Package outline



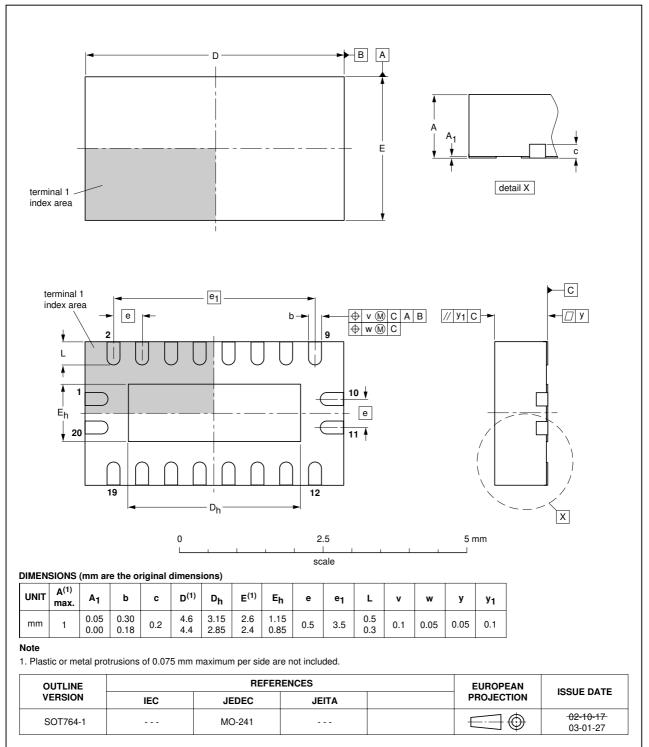
#### Fig 11. Package outline SOT163-1 (SO20)

Octal D-type flip-flop; positive edge-trigger; 3-state



#### Fig 12. Package outline SOT360-1 (TSSOP20)

Octal D-type flip-flop; positive edge-trigger; 3-state



DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

#### Fig 13. Package outline SOT764-1 (DHVQFN20)

## **13. Abbreviations**

Table 10.	Abbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 14. Revision history

#### Table 11.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74ALVC574_2	20071108	Product data sheet	-	74ALVC574_1	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>				
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>				
	<u>Section 3</u> : DHVQFN20 package added.				
	<ul> <li><u>Section 8</u>: derating values added for DHVQFN20 package.</li> </ul>				
	<ul> <li><u>Section 12</u>: outline drawing added for DHVQFN20 package.</li> </ul>				
74ALVC574_1	20020304	Product specification	-	-	

## **15. Legal information**

## 15.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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For additional information, please visit: <u>http://www.nxp.com</u>

For sales office addresses, send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

Octal D-type flip-flop; positive edge-trigger; 3-state

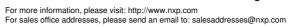
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